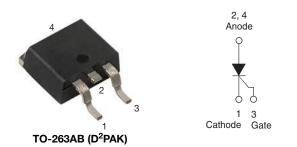


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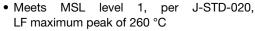
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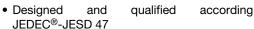
Thyristor High Voltage Surface Mount Phase Control SCR, 10 A

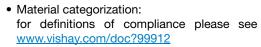


| PRODUCT SUMMARY | | | | | | |
|--------------------|-------------------------------|--|--|--|--|--|
| Package | TO-263AB (D ² PAK) | | | | | |
| Diode variation | Single SCR | | | | | |
| I _{T(AV)} | 6.5 A | | | | | |
| V_{DRM}/V_{RRM} | 800 V | | | | | |
| V_{TM} | < 1.15 V | | | | | |
| I _{GT} | 15 mA | | | | | |
| T_J | -40 to +125 °C | | | | | |

FEATURES











ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-10TTS08SPbF high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

| OUTPUT CURRENT IN TYPICAL APPLICATIONS | | | | | | | | |
|---|------|------|---|--|--|--|--|--|
| APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS | | | | | | | | |
| NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper | 2.5 | 3.5 | | | | | | |
| Aluminum IMS, R _{thCA} = 15 °C/W | 6.3 | 9.5 | A | | | | | |
| Aluminum IMS with heatsink, R _{thCA} = 5 °C/W | 14.0 | 18.5 | | | | | | |

Note

• T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|------------------------------------|-------------------------------|-------------|-------|--|--|--|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | | | | |
| I _{T(AV)} | Sinusoidal waveform | 6.5 | A | | | | | |
| I _{RMS} | | 10 | A | | | | | |
| V _{RRM} /V _{DRM} | | 800 | V | | | | | |
| I _{TSM} | | 110 | А | | | | | |
| V _T | 6.5 A, T _J = 25 °C | 1.15 | V | | | | | |
| dV/dt | | 150 | V/µs | | | | | |
| dl/dt | | 100 | A/µs | | | | | |
| TJ | Range | -40 to +125 | °C | | | | | |

| VOLTAGE RATINGS | | | |
|------------------------|---|--|---|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V | I _{RRM} /I _{DRM} AT 125 °C mA |
| VS-10TTS08SPbF | 800 | 800 | 1.0 |



| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|---|----------------------------------|---|---|-------|------------------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | | | | |
| Maximum average on-state current | I _{T(AV)} | T 110 °C 100° conduc | 6.5 | | | | | |
| Maximum RMS on-state current | I _{T(RMS)} | T _C = 112 °C, 180° conduc | tion hall sine wave | 10 | ٨ | | | |
| Maximum peak, one-cycle, | 1 | 10 ms sine pulse, rated V _I | RRM applied, T _J = 125 °C | 95 | Α | | | |
| non-repetitive surge current | I _{TSM} | 10 ms sine pulse, no volta | age reapplied, T _J = 125 °C | 110 | | | | |
| Maying up 12+ for fusing | I ² t | 10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C | | 45 | A ² s | | | |
| Maximum I ² t for fusing | 1-1 | 10 ms sine pulse, no volta | 10 ms sine pulse, no voltage reapplied, T _J = 125 °C | | | | | |
| Maximum l²√t for fusing | I ² √t | t = 0.1 ms to 10 ms, no vo | 640 | A²√s | | | | |
| Maximum on-state voltage drop | V_{TM} | 6.5 A, T _J = 25 °C | 1.15 | V | | | | |
| On-state slope resistance | r _t | T 405 00 | | 17.3 | mΩ | | | |
| Threshold voltage | V _{T(TO)} | T _J = 125 °C | | 0.85 | V | | | |
| Maximum various and divest leakers as weent | 1 // | T _J = 25 °C | V Datad V A/ | 0.05 | | | | |
| Maximum reverse and direct leakage current | I _{RM} /I _{DM} | T _J = 125 °C | V _R = Rated V _{RRM} /V _{DRM} | 1.0 | | | | |
| Typical holding current | I _H | Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C | | 30 | mA | | | |
| Maximum latching current | ΙL | Anode supply = 6 V, resis | 50 | | | | | |
| Maximum rate of rise of off-state voltage | dV/dt | $T_J = T_J \text{ max., linear to } 80^\circ$ | | V/µs | | | | |
| Maximum rate of rise of turned-on current | dl/dt | | | 100 | A/μs | | | |

| TRIGGERING | | | | | | | | |
|---|--------------------|--|--------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | |
| Maximum peak gate power | P_{GM} | | 8.0 | W | | | | |
| Maximum average gate power | P _{G(AV)} | | 2.0 | VV | | | | |
| Maximum peak positive gate current | +I _{GM} | | 1.5 | Α | | | | |
| Maximum peak negative gate voltage | -V _{GM} | | 10 | V | | | | |
| | I _{GT} | Anode supply = 6 V, resistive load, T _J = - 65 °C | 20 | mA | | | | |
| Maximum required DC gate current to trigger | | Anode supply = 6 V, resistive load, T _J = 25 °C | 15 | | | | | |
| | | Anode supply = 6 V, resistive load, T _J = 125 °C | 10 | | | | | |
| | | Anode supply = 6 V, resistive load, T _J = - 65 °C | 1.2 | | | | | |
| Maximum required DC gate voltage to trigger | V_{GT} | Anode supply = 6 V, resistive load, T _J = 25 °C | 1 | V | | | | |
| voltage to trigger | | Anode supply = 6 V, resistive load, T _J = 125 °C | 0.7 | V | | | | |
| Maximum DC gate voltage not to trigger | V_{GD} | T 105 °C V Detect value | 0.2 | | | | | |
| Maximum DC gate current not to trigger | I _{GD} | T _J = 125 °C, V _{DRM} = Rated value | 0.1 | mA | | | | |

| SWITCHING | | | | |
|-------------------------------|-----------------|-------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Typical turn-on time | t _{gt} | T _J = 25 °C | 0.8 | |
| Typical reverse recovery time | t _{rr} | T = 105 °C | 3 | μs |
| Typical turn-off time | t _q | T _J = 125 °C | 100 | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|---|-----------------------------------|---|-------------|------|--|--|--|--|
| PARAMETER | ARAMETER SYMBOL TEST CONDITIONS | | | | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -40 to +125 | °C | | | | |
| Soldering temperature | T _S | For 10 s (1.6 mm from case) | 260 | | | | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 1.5 | °C/W | | | | |
| Typical thermal resistance, junction to ambient (PCB mount) | R _{thJA} ⁽¹⁾ | | 40 | C/VV | | | | |
| Approximate weight | | | 2 | g | | | | |
| Approximate weight | | | 0.07 | OZ. | | | | |
| Marking device | | Case style D ² PAK (SMD-220) | 10TTS | 08S | | | | |

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

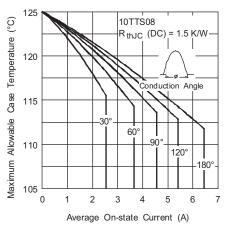


Fig. 1 - Current Rating Characteristics

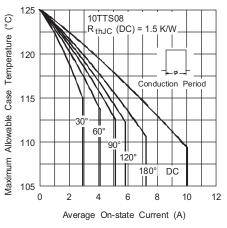


Fig. 2 - Current Rating Characteristics

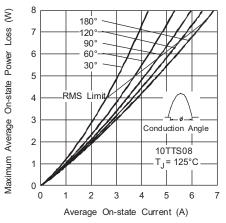


Fig. 3 - On-State Power Loss Characteristics

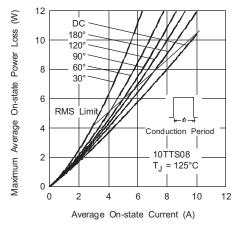


Fig. 4 - On-State Power Loss Characteristics

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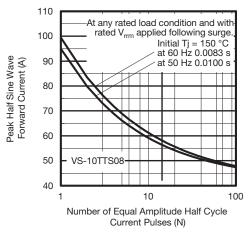


Fig. 5 - Maximum Non-Repetitive Surge Current

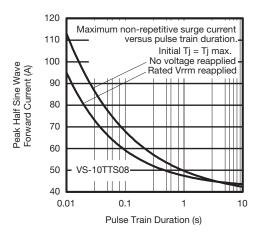


Fig. 6 - Maximum Non-Repetitive Surge Current

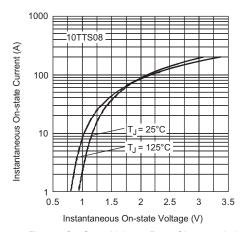


Fig. 7 - On-State Voltage Drop Characteristics

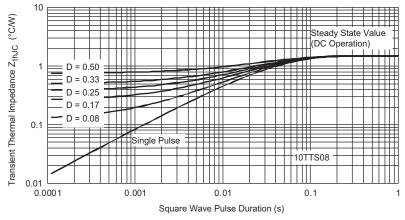
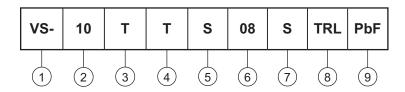


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating, RMS value
- 3 Circuit configuration:

T = single thyristor

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = converter grade

- Voltage code x 100 = V_{RRM}
- 7 S = TO-220 D²PAK (SMD-220) version
- 8 Tape and reel option:
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 9 PbF = lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | |
| VS-10TTS08SPbF | 50 | 1000 | Antistatic plastic tubes | | | | | |
| VS-10TTS08STRRPbF | 800 | 800 | 13" diameter reel | | | | | |
| VS-10TTS08STRLPbF | 800 | 800 | 13" diameter reel | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|--|--------------------------|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95046</u> | | | | | |
| Part marking information | www.vishay.com/doc?95054 | | | | |
| Packaging information | www.vishay.com/doc?95032 | | | | |



D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIM | ETERS | INC | HES | NOTES | SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|----------|--------|-------|-------|-------|-------|---------|--------|-------|-------|-------|-------|------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 |) BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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